

Sheet <u>L</u> of		FORM PTO 1449 (modified)		ATTY DOCKET NO. 282/014		SERIAL NO. 10/035,257	
U.S. DEPARTMENT OF COMMERCE		APPLICANT Byung-Hae KIM et al.					
		FILING DATE January 4, 2002				GROUP 2822	
U.S. PATENT DOCUMENTS							
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)							
MG			ZHAO et al. TiAl ₃ FORMATION BY FURNACE ANNEALING OF Ti/Al BILAYERS AND THE EFFECT OF IMPURITIES				
			April 15, 1988, J. Appl. Phys pages 2800-2807.				
MG			VOUTSAS et al. STRUCTURE ENGINEERING FOR HILLOCK-FREE PURE ALUMINUM, etc., July/Aug. 1998				
			J. Vac. Sci. Technol. pages 2668-2670.				
MG			KIM et al. "CREEP-CONTROLLED DIFFUSIONAL HILLOCK FORMATION IN BLANKET, etc., August 2000,				
			Journal of Materials Research, Vol. 15, Issue 8, pages 1709-1718.				
MG			LIU et al. FORMATION OF INTERMETALLIC NANOCOMPOSITES IN THE TiAlSi SYSTEM BY MECHANICAL, etc.,				
			May 1998, Journal of Materials Research, Vol. 13, Issue 5, pages 1198-1203.				
EXAMINER <i>Maria Guerrero</i>		DATE CONSIDERED <i>4-30-04</i>					

Sheet <u>L</u> of <u> </u>							
FORM PTO 1449 (modified) U.S. DEPARTMENT OF COMMERCE	<table border="1" style="width:100%; border-collapse: collapse;"> <tr> <td style="width:50%; padding: 2px;">ATTY DOCKET NO. 262/014</td> <td style="width:50%; padding: 2px;">SERIAL NO. 10/036,267</td> </tr> <tr> <td colspan="2" style="padding: 2px;">APPLICANT Byung-Hee KIM et al.</td> </tr> <tr> <td style="width:50%; padding: 2px;">FILING DATE January 4, 2002</td> <td style="width:50%; padding: 2px;">GROUP 2822</td> </tr> </table>	ATTY DOCKET NO. 262/014	SERIAL NO. 10/036,267	APPLICANT Byung-Hee KIM et al.		FILING DATE January 4, 2002	GROUP 2822
ATTY DOCKET NO. 262/014	SERIAL NO. 10/036,267						
APPLICANT Byung-Hee KIM et al.							
FILING DATE January 4, 2002	GROUP 2822						
U.S. PATENT DOCUMENTS							
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)							
MG			ZHAO et al. TiAl ₃ FORMATION BY FURNACE ANNEALING OF Ti/Al BILAYERS AND THE EFFECT OF IMPURITIES				
			April 15, 1988, J. Appl. Phys pages 2800-2807.				
MG			VOUTSAS et al. STRUCTURE ENGINEERING FOR HILLOCK-FREE PURE ALUMINUM, etc., July/Aug. 1998				
			J. Vac. Sci. Technol. pages 2669-2670.				
MG			KIM et al. "CREEP-CONTROLLED DIFFUSIONAL HILLOCK FORMATION IN BLANKET, etc., August 2000,				
			Journal of Materials Research, Vol. 15, Issue 8, pages 1709-1718.				
MG			LIU et al. FORMATION OF INTERMETALLIC NANOCOMPOSITES IN THE TiAl ₃ SYSTEM BY MECHANICAL, etc.,				
			May 1998, Journal of Materials Research, Vol. 13, Issue 5, pages 1198-1203.				
EXAMINER <u>Hana Guerrero</u>			DATE CONSIDERED <u>4-30-08</u>				